

M.2 2280 PCle SSD 930-D Datasheet

(SQF-C8Mxx-xxxGDEEx)

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Revision History

Rev.	Date	History
0.1	2022/5/4	Preliminary release
0.2	2022/6/23	Add performance

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Safety Instructions

- 1. Read these safety instructions carefully.
- 2. Keep this User Manual for later reference.
- 3. Disconnect this equipment from any AC outlet before cleaning. Use a damp cloth. Do not use liquid or spray detergents for cleaning.
- 4. For plug-in equipment, the power outlet socket must be located near the equipment and must be easily accessible.
- 5. Keep this equipment away from humidity.
- 6. Put this equipment on a reliable surface during installation. Dropping it or letting it fall may cause damage.
- 7. The openings on the enclosure are for air convection. Protect the equipment from overheating. DO NOT COVER THE OPENINGS.
- 8. Make sure the voltage of the power source is correct before connecting the equipment to the power outlet.
- 9. Position the power cord so that people cannot step on it. Do not place anything over the power cord.
- 10. All cautions and warnings on the equipment should be noted.
- 11. If the equipment is not used for a long time, disconnect it from the power source to avoid damage by transient overvoltage.
- 12. Never pour any liquid into an opening. This may cause fire or electrical shock.
- 13. Never open the equipment. For safety reasons, the equipment should be opened only by qualified service personnel.
- 14. If one of the following situations arises, get the equipment checked by service personnel:
 - The power cord or plug is damaged.
 - Liquid has penetrated the equipment.
 - The equipment has been exposed to moisture.
 - The equipment does not work well, or you cannot get it to work according to the user's manual.
 - The equipment has been dropped and damaged.
 - The equipment has obvious signs of breakage.
- 15. DO NOT LEAVE THIS EQUIPMENT IN AN ENVIRONMENT WHERE THE STORAGE TEMPERATURE MAY GO BELOW -20° C (-4° F) OR ABOVE 60° C (140° F). THIS COULD DAMAGE THE EQUIPMENT. THE EQUIPMENT SHOULD BE IN A CONTROLLED ENVIRONMENT.
- 16. CAUTION: DANGER OF EXPLOSION IF BATTERY IS INCORRECTLY REPLACED. REPLACE ONLY WITH THE SAME OR EQUIVALENT TYPE RECOMMENDED BY THE MANUFACTURER, DISCARD USED BATTERIES ACCORDING TO THE MANUFACTURER'S INSTRUCTIONS.

Consignes de sécurité

- 1. Lisez attentivement ces instructions de sécurité.
- 2. Conservez ce manuel pour référence ultérieure.
- 3. Débranchez cet appareil de toute prise secteur avant le nettoyage. Utilisez un chiffon humide. Ne pas utiliser de détergents liquides ou en aérosol pour le nettoyage
- 4. Pour les équipements enfichables, la prise de courant doit être située près de l'équipement et doit être facilement accessible.
- 5. Gardez cet équipement à l'abri de l'humidité.
- 6. Placez cet équipement sur une surface fiable lors de l'installation. Le laisser tomber ou le laisser tomber peut causer des dommages.
- 7. Les ouvertures sur l'enceinte sont destinées à la convection de l'air. Protégez l'équipement de la surchauffe. NE COUVREZ PAS LES OUVERTURES.
- 8. Assurez-vous que la tension de la source d'alimentation est correcte avant de connecter l'équipement à la prise de courant.
- 9. Positionnez le cordon d'alimentation de sorte que personne ne puisse marcher dessus. Ne placez rien sur le cordon d'alimentation.
- 10. Toutes les mises en garde et avertissements sur l'équipement doivent être notés..
- 11. Si l'appareil n'est pas utilisé pendant une longue période, débranchez-le de la source d'alimentation pour éviter tout dommage dû à une surtension transitoire.
- 12. Ne jamais verser de liquide dans une ouverture. Cela pourrait provoquer un incendie ou un choc électrique.
- 13. N'ouvrez jamais l'équipement. Pour des raisons de sécurité, l'équipement ne doit être ouvert que par du personnel qualifié.
- 14. Si l'une des situations suivantes se produit, faites vérifier l'équipement par le personnel de service:l:
 - · Le cordon d'alimentation ou la fiche est endommagé Liquid has penetrated the equipment.
 - L'équipement a été exposé à l'humidité.
 - L'équipement ne fonctionne pas bien ou vous ne pouvez pas le faire fonctionner conformément au manuel d'utilisation..
 - L'équipement est tombé et endommagé...
 - L'équipement présente des signes évidents de rupture.
- 15. NE PAS LAISSER CET APPAREIL DANS UN ENVIRONNEMENT O LA TEMPÉRATURE DE STOCKAGE PEUT ÊTRE INFÉRIEURE À -20 ° C (-4 ° F) OU SUPÉRIEURE À 60 ° C (140 ° F). CELA POURRAIT ENDOMMAGER L'ÉQUIPEMENT. L'ÉQUIPEMENT DOIT ÊTRE DANS UN ENVIRONNEMENT CONTRÔLÉ.
- 16. ATTENTION: DANGER D'EXPLOSION EN CAS DE REMPLACEMENT INCORRECT DE LA PILE. REMPLACEZ UNIQUEMENT AVEC LE MÊME TYPE OU LE TYPE ÉQUIVALENT RECOMMANDÉ PAR LE FABRICANT, DÉJETTEZ LES PILES UTILISÉES SELON LES INSTRUCTIONS DU FABRICANT.

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1. Overview

Advantech SQFlash 930-D series M.2 2280 PCIe SSD (Solid State Drive) delivers all the advantages of flash disk technology with PCIe Gen4 x4 interface and is fully compliant with the standard Next Generation Form Factor (NGFF) called M.2 Card Format. The SQFlash 930-D series offers a wide range capacity up to 3.8TB and its performance can reach up to 7,200 MB/s (for read) and 6,500 MB/s (for write) based on 3D TLC NAND flash with the choice of 512MB/1GB/2GB DDR4. Moreover, the power consumption of SQFlash 930-D M.2 2280 is much lower than traditional hard drives, making it the best embedded solution for new platforms.



2. Features

PCIe Interface

- Compliant with NVMe1.4
- PCIe Express Base Ver 4.0
- PCIe Gen 4 x 4 lane & backward compatible to PCIe Gen3, Gen 2 and Gen 1
- 8 IO queues supported (1 admin queue and 8 IO queue). Each IO queue supports 256 entries.
- Support power management
- Operating Voltage: 3.3V
- Support fourth LDPC generation of ECC algorithm
- AES256 \ TCG-OPAL \ TRIM \ AHCI supported
- Hardware Quick Erase supported (optional)

■ Temperature Ranges¹

- Commercial Temperature
 - 0°C to 70°C for operating
 - -40°C to 85°C for storage
- Industrial Temperature
 - -40°C to 85°C for operating
 - -40°C to 85°C for storage

*Note: 1. Based on SMART Attribute (Byte index [2:1] of PCIe-SIG standard, which measured by thermal sensor

Mechanical Specification

- Shock: 1,500G / 0.5ms

Vibration: 20G / 80~2,000Hz

■ Humidty

Humidity: up to 95% on 40°C

■ Acquired RoHS、WHQL、CE、FCC Certificate

■ Acoustic: 0 dB

■ Dimension (w/ heatsink) : 80.4 mm x 23.3 mm x 20.5 mm



3. Specification Table

■ Performance

		Sequential (MB/sec)		Random (IOPS @4K)	
		Read	Write	Read	Write
	480 GB	6,500	4,000	450K	700K
3D TLC	960 GB	7,200	6,300	750K	1000K
(BiCS5)	1920 GB	7,200	6,500	750K	1000K
	3840 GB	7,200	6,300	550K	1000K

- 1. Performance is measured on a fresh slave drive and based on the following conditions:
 - A. CrystalDiskMark 7.0.0, 1GB range, QD=16, Thread=1
 - B. IOMeter, 1GB range, 4K data size, QD=128, 16 worker, 4k aligned
- 2. Performance is based on AMD Gen4 X570 + 8 Core CPU + DDR4 (3200Hz) 16GB.
- 3. Performance may differ according to flash configuration and platform.
- 4. The tables are for reference only. Any criteria for accepting goods shall be further discussed based on different flash configurations.

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Endurance

JEDEC defined an endurance rating TBW (TeraByte Written), following by the equation below, for indicating the number of terabytes a SSD can be written which is a measurement of SSDs' expected lifespan, represents the amount of data written to the device.

TBW = [(NAND Endurance) x (SSD Capacity)] / WAF

• NAND Endurance: Program / Erase cycle of a NAND flash.

SLC: 100,000 cyclesUltra MLC: 30,000 cycles

o MLC: 3,000 cycles

 $\circ~$ 3D TLC (BiCS3/ BiCS4/ BiCS5): 3,000 cycles

• SSD Capacity: SSD physical capacity in total of a SSD.

• **WAF**: Write Amplification Factor (WAF), as the equation shown below, is a numerical value representing the ratio between the amount of data that a SSD controller needs to write and the amount of data that the host's flash controller writes. A better WAF, which is near to 1, guarantees better endurance and lower frequency of data written to flash memory.

WAF = (Lifetime write to flash) / (Lifetime write to host)

- Endurance measurement is based on JEDEC 218/219 Workload and verified with following workload conditions,
 - PreCond%full = 100%
 - Trim commands enabled
 - Random data pattern.

3D TLC (BiCS5)	WAF	TBW	DWPD*
480 GB	2.0	580	1.1
960 GB	1.9	1000	0.9
1920 GB	1.9	1600	0.7
3840 GB	TBD	TBD	TBD

^{*} Endurance of 1 drive writes per day (DWPD) for 3 years

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4. General Description

■ Error Correction Code (ECC)

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, SQFlash 930-D series PCIe SSD applies the forth generation LDPC of ECC algorithm, which can detect and correct errors occur during read process, ensure data been read correctly, as well as protect data from corruption.

Wear Leveling

NAND flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some areas get updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling is applied to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the media.

SQFlash provides advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND flash is greatly improved.

Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during the lifespan of the flash are named "Later Bad Blocks". SQFlash implements an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves the data reliability.

Power Loss Protection

Flush Manager

Power Loss Protection is a mechanism to prevent data loss during unexpected power failure. DRAM is a volatile memory and frequently used as temporary cache or buffer between the controller and the NAND flash to improve the SSD performance. However, one major concern of the DRAM is that it is not able to keep data during power failure. Accordingly, SQFlash SSD applies the Flush Manager technology, only when the data is fully committed to the NAND flash will the controller send acknowledgement (ACK) to the host. Such implementation can prevent false-positive performance and the risk of power cycling issues.

In addition, it is critical for a controller to shorten the time the in-flight data stays in the controller internal cache. Thus, SQFlash applies an algorithm to reduce the amount of data resides in the cache to provide a better performance. With Flush Manager, incoming data would only have a "pit stop" in the cache and then move to NAND flash directly. Also, the onboard DDR will be treated as an "organizer" to consolidate incoming data into groups before written into the flash to improve write amplification.

Voltage Stabilizer

While the built-in voltage detector detects an unstable power input (< 3.135 V or > 3.465 V), the controller will issue a power failure interrupt and force a Flush CMD first. At the same time, the whole internal power supply will be switched to Voltage Stabilizer immediately to ensure stable power is supplied throughout the whole drive. This ensures the Flash IC and DDR IC will not operate with unstable power which could lead to data errors or bad data integrity.

■ TRIM

TRIM is a feature which helps improve the read/write performance and speed of solid-state drives (SSD). Unlike hard disk drives (HDD), SSDs are not able to overwrite existing data, so the available space gradually becomes smaller with each use. With the TRIM command, the operating system can inform the SSD which blocks of data are no longer in use and can be removed permanently. Thus, the SSD will perform the erase action, which prevents unused data from occupying blocks all the time.

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SMART

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is an open standard that allows a hard disk drive to automatically detect its health and report potential failures. When a failure is recorded by SMART, users can choose to replace the drive to prevent unexpected outage or data loss. Moreover, SMART can inform users of impending failures while there is still time to perform proactive actions, such as copy data to another device.

Over-Provision

Over Provisioning refers to the inclusion of extra NAND capacity in a SSD, which is not visible and cannot be used by users. With Over Provisioning, the performance and IOPS (Input/Output Operations per Second) are improved by providing the controller additional space to manage P/E cycles, which enhances the reliability and endurance as well. Moreover, the write amplification of the SSD becomes lower when the controller writes data to the flash.

Thermal Throttling

Thermal Throttling function is for protecting the drive and reducing the possibility of read / write error due to overheat. The temperature is monitored by the thermal sensor. As the operating temperature continues to increase to threshold temperature, the Thermal Throttling mechanism is activated. At this time, the performance of the drive will be significantly decreased to avoid continuous heating. When the operating temperature falls below threshold temperature, the drive can resume to normal operation.

Advanced Device Security Features

Advanced Encryption Standard (AES)

An AES 256-bit encryption key is generated in the drive's security controller before the data gets stored on the NAND flash. When the controller or firmware fails, the data that is securely stored in the encryption key becomes inaccessible through the NAND flash.

OPAL 2.0 support

SQFlash 930-D series supports standard OPAL 2.0 function for advance Self-Encryption Drive (SED) feature sets. Advantech provides also user friendly interface for setting disk / system bonding to prevent SSD be used in non-authorized platforms, which is called Flash Lock function.

Secure Erase Function

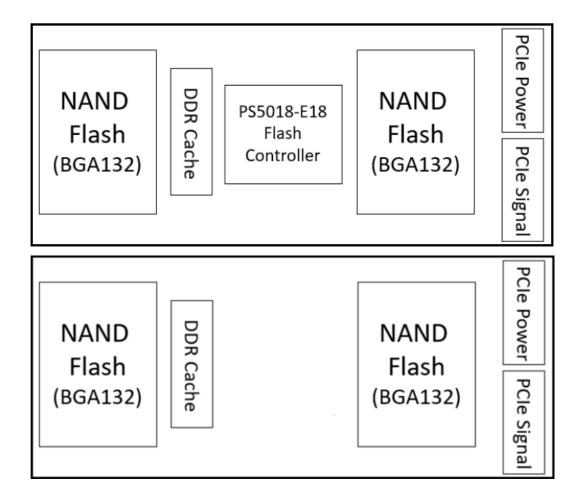
SQFlash 930-D series supports standard NVMe command for secure erase function; when the SSD controller receive the secure erase command, the erase process will reset all blocks and erase all of the user data in the SSD.

Sanitize Fucntion

SQFlash 930-D series default implement NVMe Sanitize Device Feature set, which supports the command set of Block Erase, Overwritten and Crypto Scramble. With the internal AES encryption support, the Crypto Scrambel process will start with resetting AES key. By doing so, existing data will be scrambled within 10ms and cannot be recovered anymore. Moreover, erase flag is set when erase function is triggered, which will ensure the whole erase process can be 100% completed. Even there's power interrupt, after power resume, erase operation will be resume right away as well.



Block Diagram



■ LBA value

Density (GB)	LBA
480	937,703,088
960	1,875,385,008
1920	3,750,748,848
3840	7,501,476,528

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5. Pin Assignment and Description

Pin No.	PCIe Pin	Description
1	GND	Ground
2	3.3V	3.3V source
3	GND	Ground
4	3.3V	3.3V source
5	PETn3	PCIe TX Differential signal defined by the PCI Express M.2 spec
6	N/C	No connect
7	PETp3	PCIe TX Differential signal defined by the PCI Express M.2 spec
8	N/C	No connect
9	GND	Ground
10	LED1#(O)	Open drain, active low signal. These signals are used to allow the add-in card to provide status indicators via LED devices that will be provided by the system.
11	PERn3	PCIe RX Differential signal defined by the PCI Express M.2 spec
12	3.3V	3.3V source
13	PERp3	PCIe RX Differential signal defined by the PCI Express M.2 spec
14	3.3V	3.3V source
15	GND	Ground
16	3.3V	3.3V source
17	PETn2	PCIe TX Differential signal defined by the PCI Express M.2 spec
18	3.3V	3.3V source
19	PETp2	PCIe TX Differential signal defined by the PCI Express M.2 spec
20	N/C	No connect
21	GND	Ground
22	N/C	No connect
23	PERn2	PCIe RX Differential signal defined by the PCI Express M.2 spec
24	N/C	No connect
25	PERp2	PCIe RX Differential signal defined by the PCI Express M.2 spec
26	N/C	No connect
27	GND	Ground
28	N/C	No connect
29	PETn1	PCIe TX Differential signal defined by the PCI Express M.2 spec
30	N/C	No connect
31	PETp1	PCIe TX Differential signal defined by the PCI Express M.2 spec
32	N/C	No connect
33	GND	Ground
34	N/C	No connect
35	PERn1	PCIe RX Differential signal defined by the PCI Express M.2 spec
36	N/C	No connect
37	PERp1	PCIe RX Differential signal defined by the PCI Express M.2 spec
38	N/C	No connect
39	GND CMB, CLK (VO)(0/4 9)()	Ground SMBus Clock Open Proin with null up on plotform
40	SMB_CLK (I/O)(0/1.8V)	SMBus Clock; Open Drain with pull-up on platform
41	PETn0	PCIe TX Differential signal defined by the PCI Express M.2 spec
42 43	SMB_DATA (I/O)(0/1.8V) PETp0	SMBus Data; Open Drain with pull-up on platform. PCIe TX Differential signal defined by the PCI Express M.2 spec
44	ALERT#(O) (0/1.8V)	Alert notification to master; Open Drain with pull-up on platform; Active low.
45	GND	Ground
46	N/C	No connect
47	PERn0	PCIe RX Differential signal defined by the PCI Express M.2 spec
48	N/C	No connect
49	PERp0	PCIe RX Differential signal defined by the PCI Express M.2 spec
	. =. \p0	The state of the s

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50	PERST#(I)(0/3.3V)	PE-Reset is a functional reset to the card as defined by the PCIe Mini CEM specification.
51	GND	Ground
52	CLKREQ#(I/O)(0/3.3V)	Clock Request is a reference clock request signal as defined by the PCIe Mini CEM specification; Also used by L1 PM Sub-states.
53	REFCLKn	PCIe Reference Clock signals (100 MHz) defined by the PCI Express M.2 spec.
54	PEWAKE#(I/O)(0/3.3V)	PCIe PME Wake. Open Drain with pull up on platform; Active Low.
55	REFCLKp	PCIe Reference Clock signals (100 MHz) defined by the PCI Express M.2 spec.
56	Reserved for MFG DATA	Manufacturing Data line. Used for SSD manufacturing only. Not used in normal operation. Pins should be left N/C in platform Socket.
57	GND	Ground
58	Reserved for MFG CLOCK	Manufacturing Clock line. Used for SSD manufacturing only. Not used in normal operation. Pins should be left N/C in platform Socket.
59	Module Key M	·
60	Module Key M	
61	Module Key M	
62	Module Key M	Module Key
63	Module Key M	Module Key
64	Module Key M	
65	Module Key M	
66	Module Key M	
67	N/C	No connect
68	N/C	No connect
69	N/C	PEDET (NC-PCIe)
70	3.3V	3.3V source
71	GND	Ground
72	3.3V	3.3V source
73	GND	Ground
74	3.3V	3.3V source
75	GND	Ground



6. NVMe Command List

Admin Commands

Opcode	Command Description
00h	Delete I/O Submission Queue
01h	Create I/O Submission Queue
02h	Get Log Page
04h	Delete I/O Completion Queue
05h	Create I/O Completion Queue
06h	Identify
08h	Abort
09h	Set Features
0Ah	Get Features
0Ch	Asynchronous Event Request
10h	Firmware Activate
11h	Firmware Image Download
14h	Device Self-test
80h	Format NVM
81h	Security Send
82h	Security Receive
84h	Sanitize

■ I/O Commands

Opcode	Command Description
00h	Flush
01h	Write
02h	Read
05h	Compare
08h	Write Zeroes
09h	Dataset Management

■ Set Feature Commands

Opcode	Command Description
00h	Reserved
01h	Arbitration
02h	Power Management
04h	Temperature Threshold
05h	Error Recovery
06h	Volatile Write Cache
07h	Number Of Queues
08h	Interrupt Coalescing
09h	Interrupt Vector Configuration
0Ah	Write Atomicity Normal
0Bh	Asynchronous Event Configuration
0Ch	Autonomous Power State Transition
0Eh	Timestamp
10h	Host Controlled Thermal Management
11h	Non-Operational Power State Config
0Eh – 7Dh	Reserved
80h	Software Progress Marker

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■ Get Log Page Commands

Opcode	Command Description
00h	Reserved
01h	Error Information
02h	SMAART / Health Information
03h	Firmware Slot Information
04h	Changed Namespace List
06h	Device Self-test
09h – 7Fh	Reserved
81h	Sanitize Status
82h - FFh	Reserved



7. Identify Device Data

The Identity Device Data enables Host to receive parameter information from the device. The parameter words in the buffer have the arrangement and meanings defined in below table. All reserve bits or words are zero

■ Identify Controller Data Structure

Bytes	Description
	Controller Capabilities and Features
01:00	PCI Vendor ID (VID)
03:02	PCI Subsystem Vendor ID (SSVID)
23:04	Serial Number (SN)
63:24	Model Number (MN)
71:64	Firmware Revision (FR)
72	Recommended Arbitration Burst (RAB)
75:73	IEEE OUI Identifier (IEEE)
76	Controller Multi-Path I/O and Namespace Sharing Capabilities (CMIC)
77	Maximum Data Transfer Size (MDTS)
79:78	Controller ID (CNTLID)
83:80	Version (VER)
87:84	RTD3 Resume Latency (RTD3R)
91:88	RTD3 Entry Latency (RTD3E)
95:92	Optional Asynchronous Events Supported (OAES)
99:96	Controller Attributes (CTRATT)
101:100	Read Recovery Level support bitmap (rrls)
110:102	Reserved
111	Controller Type, if support NVMe 1.4 shall be set to other than 0 (cntrltype)
127:112	FRU Globally Unique Identifier (fguid[16])
129:128	Command Retry Delay Time 1 (crdt1)
131:130	Command Retry Delay Time 2 (crdt2)
133:132	Command Retry Delay Time 3 (crdt3)
255:134	Reserved
257:256	Optional Admin Command Support (OACS)
258	Abort Command Limit (ACL)
259	Asynchronous Event Request Limit (AERL)
260	Firmware Updates (FRMW)
261	Log Page Attributes (LPA)
262	Error Log Page Entries (ELPE)
263	Number of Power States Support (NPSS)
264	Admin Vendor Specific Command Configuration (AVSCC)
265	Autonomous Power State Transition Attributes (APSTA)
267:266	Warning Composite Temperature Threshold (WCTEMP)
269:268	Critical Composite Temperature Threshold (CCTEMP)
271:270	Maximum Time for Firmware Activation (MTFA)
275:272	Host Memory Buffer Preferred Size (HMPRE)
279:276	Host Memory Buffer Minimum Size (HMMIN)
295:280	Total NVM Capacity (TNVMCAP)
311:296	Unallocated NVM Capacity (UNVMCAP)
315:312	Replay Protected Memory Block Support (RPMBS)
317:316	Extended Device Self-test Time (edstt)
318	Device Self-test Options (dsto)
319	Firmware Update Granularity (fwug)
321:320	Keep Alive Support (kas)
323:322	Host Controlled Thermal Management Attributes (hctma)
325:324	Minimum Thermal Management Temperature (mntmt)
327:326	Maximum Thermal Management Temperature (mxtmt)

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331:328	Sanitize Capabilities (sanicap)			
335:332	Host Memory Buffer Min. Descriptor Entry Size (hmminds)			
337:336	Host Memory Maximum Descriptor Entries (hmmaxd)			
339:338	NVM Set ID Maximum (nsetidmax)			
341:340	Endurance Group ID Maximum (endgidmax)			
342	ANA Maximum Transition Time (anatt)			
343	Asymmetric Namespace Access Capabilities (anacap)			
347:344	ANA Group ID Maximum (anagrpmax)			
351:348	Number of ANA Group IDs (nanagrpid)			
355:352	Persistent Event Log Size (pels)			
511:356	Reserved			
NVM Commar	nd Set Attributes			
512	Submission Queue Entry Size (SQES)			
513	Completion Queue Entry Size (CQES)			
515:514	Maximum Outstanding Commands (maxcmd)			
519:516	Number of Namespaces (NN)			
521:520	Optional NVM Command Support (ONCS)			
523:522	Fused Operation Support (FUSES)			
524	Format NVM Attributes (FNA)			
525	Volatile Write Cache (VWC)			
527:526	Atomic Write Unit Normal (AWUN)			
529:528	Atomic Write Unit Power Fail (AWUPF)			
530	NVM Vendor Specific Command Configuration (NVSCC)			
531	Namespace Write Protection Capabilities (nwpc)			
533:532	Atomic Compare & Write Unit (ACWU)			
535:534	Reserved			
539:536	SGL Support (SGLS)			
	Maximum Number of Allowed Namespace, if supports ANA Reporting shall not			
543:540	be 0 and less than NN (mnan)			
	to o and rose than the (milan)			
767:544	Reserved			
767:544	Reserved Set Attributes			
IO Command	Set Attributes			
10 Command 1023:768	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn)			
10 Command 1023:768 1791:1024	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved			
10 Command 1023:768 1791:1024 2047:1792	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification			
10 Command 1023:768 1791:1024 2047:1792 2079:2048	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0)			
10 Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1)			
10 Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432	NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD12)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD12) Power State 12 Descriptor (PSD13)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD12) Power State 13 Descriptor (PSD13) Power State 14 Descriptor (PSD14)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD7) Power State 9 Descriptor (PSD8) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD13) Power State 13 Descriptor (PSD14) Power State 14 Descriptor (PSD15)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528 2591:2560	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD7) Power State 9 Descriptor (PSD8) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD13) Power State 14 Descriptor (PSD14) Power State 15 Descriptor (PSD15) Power State 15 Descriptor (PSD15) Power State 16 Descriptor (PSD16)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528 2591:2560 2623:2592	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD8) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD13) Power State 13 Descriptor (PSD14) Power State 15 Descriptor (PSD15) Power State 16 Descriptor (PSD16) Power State 16 Descriptor (PSD17)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528 2591:2560 2623:2592 2655:2624	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD12) Power State 13 Descriptor (PSD13) Power State 14 Descriptor (PSD14) Power State 15 Descriptor (PSD15) Power State 16 Descriptor (PSD15) Power State 17 Descriptor (PSD17) Power State 18 Descriptor (PSD17) Power State 18 Descriptor (PSD17)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528 2591:2560 2623:2592 2655:2624 2687:2656	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD11) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD13) Power State 13 Descriptor (PSD13) Power State 14 Descriptor (PSD14) Power State 15 Descriptor (PSD15) Power State 16 Descriptor (PSD15) Power State 17 Descriptor (PSD16) Power State 18 Descriptor (PSD17) Power State 18 Descriptor (PSD18) Power State 19 Descriptor (PSD18)			
IO Command 1023:768 1791:1024 2047:1792 2079:2048 2111:2080 2143:2112 2175:2144 2207:2176 2239:2208 2271:2240 2303:2272 2335:2304 2367:2336 2399:2368 2431:2400 2463:2432 2495:2464 2527:2496 2559:2528 2591:2560 2623:2592 2655:2624	Set Attributes NVM Subsystem NVMe Qualified Name (subnqn) Reserved Refer to the NVMe over Fabrics specification Power State 0 Descriptor (PSD0) Power State 1 Descriptor (PSD1) Power State 2 Descriptor (PSD2) Power State 3 Descriptor (PSD3) Power State 4 Descriptor (PSD4) Power State 5 Descriptor (PSD5) Power State 6 Descriptor (PSD6) Power State 7 Descriptor (PSD7) Power State 8 Descriptor (PSD8) Power State 9 Descriptor (PSD9) Power State 10 Descriptor (PSD10) Power State 11 Descriptor (PSD11) Power State 12 Descriptor (PSD12) Power State 13 Descriptor (PSD13) Power State 14 Descriptor (PSD14) Power State 15 Descriptor (PSD15) Power State 16 Descriptor (PSD15) Power State 17 Descriptor (PSD17) Power State 18 Descriptor (PSD17) Power State 18 Descriptor (PSD17)			

Specifications subject to change without notice, contact your sales representatives for the most update information.



2783:2752	Power State 22 Descriptor (PSD22)	
2815:2784	Power State 23 Descriptor (PSD23)	
2847:2816	Power State 24 Descriptor (PSD24)	
2879:2848	Power State 25 Descriptor (PSD25)	
2911:2880	Power State 26 Descriptor (PSD26)	
2943:2912	Power State 27 Descriptor (PSD27)	
2975:2944	Power State 28 Descriptor (PSD28)	
3007:2976	Power State 29 Descriptor (PSD29)	
3039:3008	Power State 30 Descriptor (PSD30)	
3071:3040	Power State 31 Descriptor (PSD31)	
Vendor Specific		
4095:3072	Vendor Specific (VS)	



■ Identify Namespace Data Structure & NVM Command Set Specific

Bytes	Description
7:0	Namespace Size (NSZE)
15:8	Namespace Capacity (NCAP)
23:16	Namespace Utilization (NUSE)
24	Namespace Features (NSFEAT)
25	Number of LBA Formats (NLBAF)
26	Formatted LBA Size (FLBAS)
27	Metadata Capabilities (MC)
28	End-to-end Data Protection Capabilities (DPC)
29	End-to-end Data Protection Type Settings (DPS)
30	Namespace Multi-path I/O and Namespace Sharing Capabilities (NMIC)
31	Reservation Capabilities (RESCAP)
32	Format Progress Indicator (FPI)
33	Deallocate Logical Block Features (dlfeat)
35:34	Namespace Atomic Write Unit Normal (NAWUN)
37:36	Namespace Atomic Write Unit Power Fail (NAWUPF)
39:38	Namespace Atomic Compare & Write Unit (NACWU)
41:40	Namespace Atomic Boundary Size Normal (NABSN)
43:42	Namespace Atomic Boundary Offset (NABO)
45:44	Namespace Atomic Boundary Size Power Fail (NABSPF)
47:46	Namespace Optimal IO Boundary (noiob)
64:48	NVM Capacity (NVMCAP)
65:64	Namespace Preferred Write Granularity (npwg)
69:68	Namespace Preferred Deallocation(Trim) Granularity (npdg)
71:70	Namespace Preferred Deallocation(Trim) Alignment (npda)
73:72	Namespace Optimal Write Size (nows)
91:74	Reserved
95:92	ANA Groput Identifier (anagrpid)
98:96	Reserved
99	Namespace Attributes (nsattr)
101:100	NVM Set Identifier (nvmsetid)
103:102	Endurange Group Identifier // NVMe 1.4 add (endgid)
119:104	Namespace Globally Unique Identifier (NGUID)
127:120	IEEE Extended Unique Identifier (EUI64)
131:128	LBA Format 0 Support (LBAF0)
135:132	LBA Format 1 Support (LBAF1)
139:136	LBA Format 2 Support (LBAF2)
143:140	LBA Format 3 Support (LBAF3)
147:144	LBA Format 4 Support (LBAF4)
151:148	LBA Format 5 Support (LBAF5)
155:152	LBA Format 6 Support (LBAF6)
159:156	LBA Format 7 Support (LBAF7)
163:160	LBA Format 8 Support (LBAF8)
167:164	LBA Format 9 Support (LBAF9)
171:168	LBA Format 10 Support (LBAF10)
175:172	LBA Format 11 Support (LBAF11)
179:176	LBA Format 12 Support (LBAF12)
183:180	LBA Format 13 Support (LBAF13)
187:184	LBA Format 14 Support (LBAF14)
191:188	LBA Format 15 Support (LBAF15)
383:192	Reserved
4095:384	Vendor Specific (VS)

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List of Identify Namespace Data Structure for Each Capacity

Capacity	Byte[7:0]:
(GB)	Namespace Size (NSZE)
480	37E436B0h
960	6FC81AB0h
1920	DF8FE2B0h
3840	1BF1F72B0h

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8. SMART Atrributes

ID	ATTRIBUTE_NAME	Log Identifier	# of Bytes	Byte index	Unit
01h	Critical Warning	02h	1	[0]	-
02h	Composite Temperature	02h	2	[2:1]	°K
03h	Available Spare	02h	1	[3]	%
04h	Available Spare Threshold	02h	1	[4]	%
05h	Percentage Used	02h	1	[5]	%
06h-10h	Reserved	02h		[31:6]	
11h	Data Units Read	02h	16	[47:32]	1000 Sectors
12h	Data Units Written (Host Write)	02h	16	[63:48]	1000 Sectors
13h	Host Read Commands	02h	16	[79:64]	count
14h	Host Write Commands	02h	16	[95:80]	count
15h	Controller Busy Time	02h	16	[111:96]	mins
16h	Power Cycles	02h	16	[127:112]	count
17h	Power on Hours	02h	16	[143:128]	hours
18h	Unsafe Shutdowns	02h	16	[159:144]	count
19h	Media and Data Integrity Errors	02h	16	[175:160]	times
1Ah	Number of Error Information Log Entries	02h	16	[191:176]	count
1Bh	Warning Composite Temperature Time	02h	4	[195:192]	mins
1Ch	Critical Composite Temperature Time	02h	4	[199:196]	mins
1Dh	Temperature Sensor 1	02h	2	[201:200]	°K
1Eh	Temperature Sensor 2	02h	2	[203:202]	°K
1Fh	Temperature Sensor 3	02h	2	[205:204]	°K
20h	Temperature Sensor 4	02h	2	[207:206]	°K
21h	Temperature Sensor 5	02h	2	[209:208]	°K
22h	Temperature Sensor 6	02h	2	[211:210]	°K
23h	Temperature Sensor 7	02h	2	[213:212]	°K
24h	Temperature Sensor 8	02h	2	[215:214]	°K
25h	Thermal Management Temperature 1 Transition Count	02h	4	[219:216]	count
26h	Thermal Management Temperature 2 Transition Count	02h	4	[223:220]	count
27h	Total Time for Thermal Management Temperature 1:	02h	4	[227:224]	Second
28h	Total Time for Thermal Management Temperature 2:	02h	4	[231:228]	Second
29h-4Fh	Reserved	02h		[511:232]	
50h	Flash Read Sector	C0h	8	[7:0]	sector
51h	Flash Write Sector	C0h	8	[15:8]	sector
52h	UNC Error	C0h	8	[23:16]	count
53h	PHY Error	C0h	4	[27:24]	count
54h	Early Bad Block	C0h	4	[31:28]	count
55h	Later Bad Block	C0h	4	[35:32]	count

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56h	Max Erase Count	C0h	4	[39:36]	count
57h	Average Erase Count	C0h	4	[43:40]	count
58h	Current Percent Spares	C0h	8	[51:44]	%
59h	Current Temperature	C0h	2	[53:52]	°K
5Ah	Lowest Temperature	C0h	2	[55:54]	°K
5Bh	Highest Temperature	C0h	2	[57:56]	°K
5Ch	Current Controller Temperature	C0h	2	[61:60]	°K
5Dh	Spare Blocks	C0h	2	[63:62]	count

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9. System Power Consumption

■ Supply Voltage

Parameter	Rating	
Operating Voltage	3.3V	

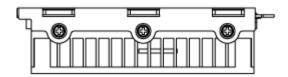
■ Power Consumption

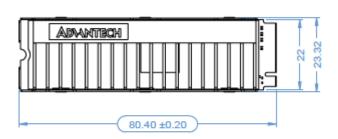
(Unit: W)		Read	Write	ldle
	480 GB	8.9	7.6	3
3D TLC	960 GB	10.2	9.5	3
(BiCS5)	1920 GB	10.7	10.6	3
	3840 GB	11	11	3

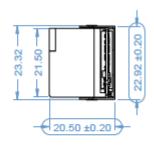
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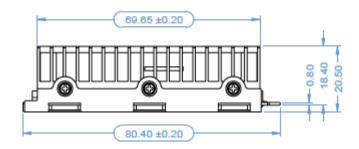


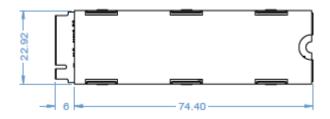
10. Physical Dimension M.2 2280 PCIe SSD (w/ Heatsink) (Unit: mm)











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Appendix: Part Number Table

Product	Advantech PN
SQF 930-D NVMe M.2 2280 SSD (OPAL) 480G 3D TLC (BiCS5) (0~70°C)	SQF-C8MV4-480GDEEC
SQF 930-D NVMe M.2 2280 SSD (OPAL) 960G 3D TLC (BiCS5) (0~70°C)	SQF-C8MV4-960GDEEC
SQF 930-D NVMe M.2 2280 SSD (OPAL)1920G 3D TLC (BiCS5) (0~70°C)	SQF-C8MV4-1K9GDEEC
SQF 930-D NVMe M.2 2280 SSD (OPAL) 3840G 3D TLC (BiCS5) (0~70°C)	SQF-C8MV4-3K8GDEEC
SQF 930-D NVMe M.2 2280 SSD (OPAL) 480G 3D TLC (BiCS5) (-40~85°C)	SQF-C8MV4-480GDEEE
SQF 930-D NVMe M.2 2280 SSD (OPAL) 960G 3D TLC (BiCS5) (-40~85°C)	SQF-C8MV4-960GDEEE
SQF 930-D NVMe M.2 2280 SSD (OPAL)1920G 3D TLC (BiCS5) (-40~85°C)	SQF-C8MV4-1K9GDEEE
SQF 930-D NVMe M.2 2280 SSD (OPAL) 3840G 3D TLC (BiCS5) (-40~85°C)	SQF-C8MV4-3K8GDEEE

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Mouser Electronics

Authorized Distributor

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Advantech:

SQF-C8MV4-960GDEE SQF-C8MV4-960GDEE SQF-C8MV4-3K8GDEE SQF-C8MV4-1K9GDEEC SQF-C8MV4-1K9GDEEC SQF-C8MV4-480GDEE SQF-C8MV4-480GDEEC SQF-C8ME4-960GDEEC SQF-C8ME4-480GDEEC SQF-C8ME4-480GDEEC SQF-C8ME4-480GDEEC